

USB Host Charger Identification Analog Switches

General Description

The SLG55596A is a USB device that combines high speed USB switches with a USB host charger (dedicated charger) identification circuit. The device supports both the latest USB Battery Charging Specification Revision 1.2 including data contact detection and a set resistor bias for Apple* compliant devices as well as legacy USB D+/D- short detection using data line pull-up.

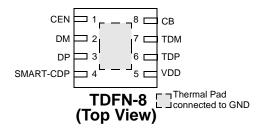
The SLG55596A can also support CDP mode (FAST charging and data communication available mode if smartphone can support CDP mode).

The SLG55596A can also support low speed / full speed mouse/keyboard wake-up from S3 mode.

Features

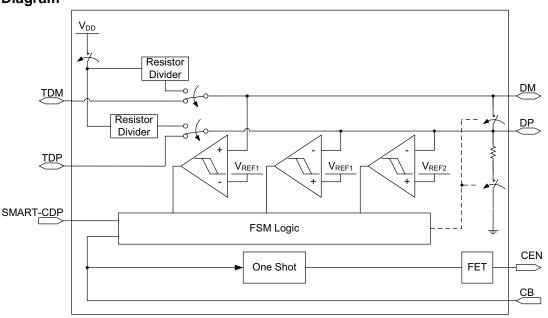
- · High Speed USB Switching
- Low 4.0pF (typ) On Capacitance
- Low 4.0Ω (typ) On Resistance
- Low 0.5Ω (typ) On Resistance Flatness
- 4.5V to 5.5V Supply Range
- Low Supply Current
- · Automatic Current-Limit Switch Control
- · Automatic USB Charger Identification Circuit
- CDP Support (active USB 2.0 data communication with 1.5A charging)
- Apple iPad* @ 2.4A charging current support
- Automatic CDP/SDP mode support with SMART-CDP=1 for "Always Data Communication"
- Chinese Telecom Standard YD/T 1591-2009 specification support
- Samsung Galaxy Tab** charge scheme support
- Pb-Free / RoHS Compliant / Halogen-Free
- TDFN-8 Package

Pin Configuration - SLG55596A



- * Apple iPhone, iPad and iPod are trademarks of Apple Inc., registered in the
- ** Samsung Galaxy Tab are trademarks of Samsung Electronics, registered in Korea and other countries.

Block Diagram







Pin Description - SLG55596A

Pin#	Pin Name	Туре	Pin Description
1	CEN	Output	N-FET Open Drain Output. Current Limit Switch (CLS) Control Output. CB changes from 0 to 1 or 1 to 0. CEN will be low for 2 seconds (typ)
2	DM	Input/Output	USB Connector D-
3	DP	Input/Output	USB Connector D+
4	SMART-CDP	Input	Input Control logic (see truth table)
5	VDD	PWR	Power Supply. Connect a $0.1\mu F$ capacitor between VDD and GND as close as possible to the device.
6	TDP	Input/Output	Host USB Transceiver D+ Connection
7	TDM	Input/Output	Host USB Transceiver D- Connection
8	СВ	Input	Switch Control Bit 0 = autodetection charger identification active 1 = charging downstream port with active USB2.0 data communication mode with 1.5A support
9	Thermal Pad	GND	Ground

Truth Table

СВ	SMART-CDP	Function
0	0 or 1	DCP autodetect with mouse/keyboard wakeup (Pin 4 = 0 or 1)
1	0	S0 charging with SDP only
1	1	S0 charging with CDP or SDP only (depending on external device) And, when Non-CDP phone is plugged in, the CDP mode will be changed automatically to SDP mode during handshaking protocol for supporting data communication.

Ordering Information

Part Number	Туре
SLG55596AV	TDFN-8
SLG55596AVTR	TDFN-8 - Tape and Reel

000-0055596-10 Page 2 of 10





Absolute Maximum Ratings

Parameter	Min.	Max.	Unit
Supply Voltage	-0.3	6.0	V
Continuous Current into any terminal	-30	+30	mA
Continuous Power Dissipation		954	mW
Operating Temperature Range	-40	85	°C
Junction Temperature		150	°C
Storage Temperature Range	-65	150	°C
Lead Temperature (Soldering, 10s)		260	°C

Note: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics - Power Supply

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
V _{DD} Power Supp	Dawer Cumby Dame	V _{CB} > V _{IH}	4.5	5.0	5.5	V
	Supply Range	V _{CB} = 0V	4.75		5.25	V
I _{DD}	Supply Current V _{DD} = 5V	CB = LOW, SMART-CDP = X (autodetect with wakeup)		140	160	μΑ
		CB = HIGH, SMART-CDP = LOW (SDP)		20	30	μΑ
		CB = HIGH, SMART-CDP = HIGH (CDP)		30	50	μΑ

Electrical Characteristics - Analog Switch

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
V _{DP} , V _{DM}	Analog signal Range		0		V _{DD}	V
		$V_{DD} = -0.4V$ to 0.4V, I = 10mA		3.5		Ω
R _{ON}	On Resistance TDP/TDM Switch	$V_{DP} = V_{DM} = 0V \text{ to } 3.3V$ $V_{DD} = 5V$		4.0	7	Ω
ΔR_{ON}	On Resistance Match between channels TDP/TDM Switch	$\begin{aligned} V_{DD} &= 5.0V \\ V_{DP} &= V_{DM} = 400 \text{mV} \\ I_{DP} &= I_{DM} = 10 \text{mA} \end{aligned}$		0.1		Ω
R _{FLAT}	On Resistance flatness TDP/TDM Switch	$V_{DD} = 5.0V$ $V_{DP} = V_{DM} = 0V \text{ to } V_{DD}$ $I_{DP} = I_{DM} = 10\text{mA}$		0.5		Ω
R _{SHORT}	On Resistance of TDP/TDM Short	$V_{CB} = 0V$ $V_{DP} = 1V$ $I_{DP} = I_{DM} = 10mA$		50	70	Ω
I _{TDPOFF} , I _{TDMOFF}	Off-Leakage Current	$V_{DD} = 3.6V$ $V_{DP} = V_{DM} = 0.3V$ to 3.3V $V_{TDP} = V_{TDM} = 3.3V$ to 0.3V $V_{CB} = 0V$	-250		250	nA
I _{DPON} , I _{DMON}	Off-Leakage Current	$V_{DD} = 3.6V$ $V_{DP} = V_{DM} = 3.3V$ to 0.3V $V_{CB} = V_{DD}$	-250		250	nA

000-0055596-10 Page 3 of 10





Electrical Characteristics - Dynamic Performance

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
T _{ON}	Turn On Time	V_{TDP} or $V_{TDM} = 1.5V$ $R_L = 300\Omega$ $C_L = 35pF$	'	20	100	μs
T _{OFF}	Turn Off Time	V_{TDP} or $V_{TDM} = 1.5V$ $R_L = 300\Omega$ $C_L = 35pF$	'	1	5	μs
T _{PLH} , T _{PHL}	TDP/TDM Switch Propagation Delay	$R_L = R_S = 50\Omega$		60		ps
T _{SKEW}	Output Skew	Skew between DP and DM when connected to TDP and TDM $R_L = R_S = 50\Omega$		40		ps
C _{OFF}	TDP/TDM Off-Capacitance	f = 1MHz	"	2.0		pF
C _{ON}	DP/DM On-Capacitance	f = 240MHz	'	4.0	5.5	pF
BW	-3dB Bandwidth	$R_L = R_S = 50\Omega$		1000		MHz
V _{ISO}	Off-Isolation	V_{TDP} , $V_{DP} = 0$ dBm $R_L = R_S = 5 0\Omega$ f = 250MHz		-20		dB
V _{CT}	Crosstalk	V_{TDP} , $V_{DP} = 0$ dBm $R_L = R_S = 50\Omega$ f = 250MHz		-25		dB

Electrical Characteristics - Internal Resistors

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
R _{PD}	DP/DM Short Pull-down		350	500	700	kΩ
RT _{RP}	RP1/RP2 Ratio		0.8544	0.863	0.872	Ratio
R _{RP}	RP1 + RP2 Resistance		69.75	93.0	115.18	kΩ
RT _{RM}	RM1/RM2 Ratio		0.8544	0.863	0.872	Ratio
R _{RM}	RM1 + RM2 Resistance		69.75	93.0	115.18	kΩ

Electrical Characteristics - Logic Input CB

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
V _{IH}	CB Input Logic High		1.4			V
V _{IL}	CB Input Logic Low				0.4	V
I _{IN}	CB Input Leakage Current	$V_{DD} = 5.5V$ $0 \le V_{CB} \le V_{IL}$ or $V_{IH} \le V_{CB} \le V_{DD}$	-1		1	μА

000-0055596-10 Page 4 of 10



Electrical Characteristics - Logic Input SMART-CDP

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
V _{IH}	SMART-CDP input Logic High		3.0			V
V _{IL}	SMART-CDP input Logic Low				0.8	V
I _{IN}	SMART-CDP Input Leakage Current	$V_{DD} = 5.5V$ $0V < V_{SMART-CDP} < V_{IL}$ or $V_{IH} < V_{SMART-CDP} < V_{DD}$	-1	-	1	μА

Electrical Characteristics - CEN Outputs

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
T _{VBT}	V _{BUS} Toggle Time	CB = Logic 0 to Logic 1 or Logic 1 to Logic 0	1.5	2.0	2.5	s
V _{OL_CEN}	CEN Output Logic Low Voltage	CB = Logic 0 to Logic 1 I _{SINK} = 2mA			0.4V	V
I _{OUT_CEN}	CEN Output Leakage Current	$V_{DD} = 5.5V$ $V_{CEN} = 5.5V$ or CEN deasserted			1	μΑ

Electrical Characteristics - ESD Protection

 $V_{DD} = 4.5V$ to 5.5V, $T_A = 25^{\circ}C$ (unless specified otherwise)

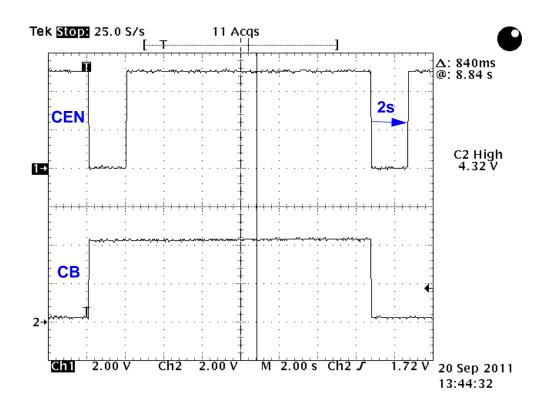
Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
V _{ESD}	ESD Protection Level (DP and DM Only)	Human Body Model		±8		kV
V _{ESD}	ESD Protection Level (All other pins)	Human Body Model		±2		kV

000-0055596-10 Page 5 of 10





CEN Function Waveform

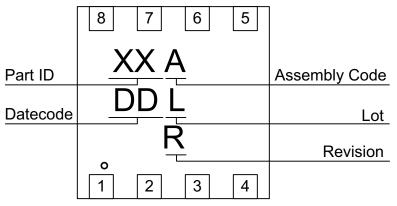


000-0055596-10 Page 6 of 10





Package Top Marking System Definition



XX - Part ID Field: identifies the specific device configuration A - Assembly Code Field: Assembly Location of the device. DD - Date Code Field: Coded date of manufacture

L - Lot Code: Designates Lot #

R - Revision Code: Device Revision

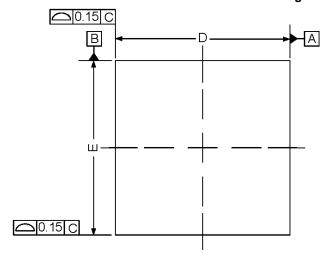
000-0055596-10 Page 7 of 10



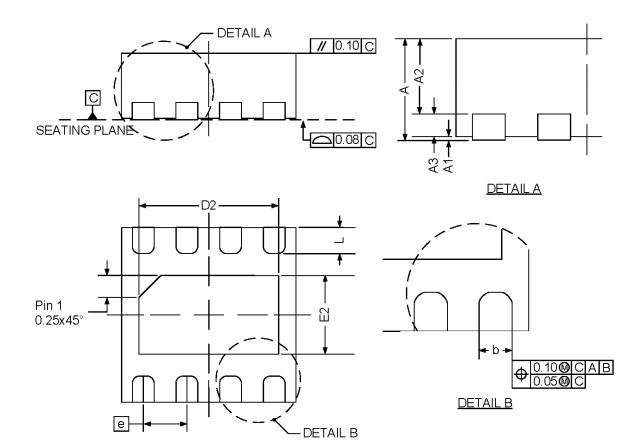


Package Drawing and Dimensions

8 Lead TDFN Package JEDEC MO-229, Variation WCCD IC Net Weight: 0.0095



Symbol	Min (mm)	NOM (mm)	Max (mm)			
Α	0.70	0.75	0.80			
A1	0.00		0.05			
A2		0.55				
А3		0.20				
b	0.20	0.25	0.30			
D	1.90	2.00	2.10			
D2	1.50	1.60	1.70			
E	1.90	2.00	2.10			
E2	0.80	0.90	1.00			
е	0.50 BSC					
Ĺ	0.20	0.30 0.40				



000-0055596-10 Page 8 of 10



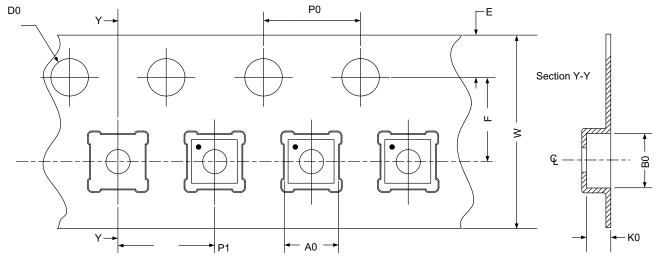


Tape and Reel Specifications

3	# of Pins	Nominal Package Size [mm]	Max Units		Reel &	Leader (min)		Trailer (min)		Таре	Part
			per Reel	per Box	Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
TDFN 8L Green	8	2 x 2 x 0.75	3,000	3,000	178 / 60	100	400	100	400	8	4

Carrier Tape Drawing and Dimensions

Package Type	PocketBTM Length	PocketBTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge		Tape Width
	A0	В0	K0	P0	P1	D0	E	F	w
TDFN 8L Green	2.3	2.3	1.05	4	4	1.55	1.75	3.5	8



Refer to EIA-481 specification

Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 3.00 mm³ (nominal). More information can be found at www.jedec.org.

000-0055596-10 Page 9 of 10



SLG55596A

Silego Website & Support

Silego Technology Website

Silego Technology provides online support via our website at http://www.silego.com/. This website is used as a means to make files and information easily available to customers.

For more information regarding Silego Green products, please visit:

http://greenpak.silego.com/ http://greenfet.silego.com/ http://greenpak2.silego.com/ http://greenfet2.silego.com/ http://greenclk.silego.com/

Products are also available for purchase directly from Silego at the Silego Online Store at http://store.silego.com/.

Silego Technical Support

Datasheets and errata, application notes and example designs, user guides, and hardware support documents and the latest software releases are available at the Silego website or can be requested directly at info@silego.com.

For specific GreenPAK design or applications questions and support please send e-mail requests to GreenPAK@silego.com

Users of Silego products can receive assistance through several channels:

Online Live Support

Silego Technology has live video technical assistance and sales support available at http://www.silego.com/. Please ask our live web receptionist to schedule a 1 on 1 training session with one of our application engineers.

Contact Your Local Sales Representative

Customers can contact their local sales representative or field application engineer (FAE) for support. Local sales offices are also available to help customers. More information regarding your local representative is available at the Silego website or send a request to info@silego.com

Contact Silego Directly

Silego can be contacted directly via e-mail at info@silego.com or user submission form, located at the following URL:

http://support.silego.com/

Other Information

The latest Silego Technology press releases, listing of seminars and events, listings of world wide Silego Technology offices and representatives are all available at http://www.silego.com/

THIS PRODUCT HAS BEEN DESIGNED AND QUALIFIED FOR THE CONSUMER MARKET. APPLICATIONS OR USES AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS ARE NOT AUTHORIZED. SILEGO TECHNOLOGY DOES NOT ASSUME ANY LIABILITY ARISING OUT OF SUCH APPLICATIONS OR USES OF ITS PRODUCTS. SILEGO TECHNOLOGY RESERVES THE RIGHT TO IMPROVE PRODUCT DESIGN, FUNCTIONS AND RELIABILITY WITHOUT NOTICE.

000-0055596-10 Page 10 of 10